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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/530,063	03/31/2005	Philippe Meunier-Beillard	BE02 0027 US	6267	
65913 NXP, B.V.	7590 12/12/200	7	EXAMINER		
NXP INTELLE	ECTUAL PROPERTY	ESTRADA, MICHELLE			
M/S41-SJ 1109 MCKAY	DRIVE	ART UNIT	PAPER NUMBER		
SAN JOSE, CA 95131			2823		
			NOTIFICATION DATE	DELIVERY MODE	
			12/12/2007	ELECTRONIC	

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

Notice of the Office communication was sent electronically on above-indicated "Notification Date" to the following e-mail address(es):

ip.department.us@nxp.com

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		Application No.	Applicant(s)			
Office Action Summary		10/530,063	MEUNIER-BEILLARD ET AL.			
		Examiner	Art Unit			
		Michelle Estrada	2823			
Period fo	The MAILING DATE of this communication apport Reply	pears on the cover sheet with the o	orrespondence address			
WHIC - Exte after - If NC - Failu Any	CORTENED STATUTORY PERIOD FOR REPLY CHEVER IS LONGER, FROM THE MAILING DATES IN A COMMENT OF THE MAILING THE MAI	ATE OF THIS COMMUNICATION 36(a). In no event, however, may a reply be tin will apply and will expire SIX (6) MONTHS from to, cause the application to become ABANDONE	N. nely filed the mailing date of this communication. ED (35 U.S.C. § 133).			
Status						
1)⊠	Responsive to communication(s) filed on <u>02 O</u>	october 2007.				
· —	This action is FINAL . 2b) This action is non-final.					
3)[Since this application is in condition for allowance except for formal matters, prosecution as to the merits is					
	closed in accordance with the practice under E	Ex parte Quayle, 1935 C.D. 11, 4	53 O.G. 213.			
Disposit	ion of Claims					
4)⊠	Claim(s) 4,5,7,18 and 19 is/are pending in the	application.				
	4a) Of the above claim(s) is/are withdrawn from consideration.					
5)	Claim(s) is/are allowed.					
	Claim(s) 4,7 and 18 is/are rejected.					
·	Claim(s) <u>5 and 19</u> is/are objected to.					
8)	Claim(s) are subject to restriction and/o	or election requirement.				
Applicat	ion Papers					
,	The specification is objected to by the Examine					
10)	The drawing(s) filed on is/are: a) acc					
	Applicant may not request that any objection to the	- · ·				
11)	Replacement drawing sheet(s) including the correct The oath or declaration is objected to by the Ex					
Priority	under 35 U.S.C. § 119					
12)	Acknowledgment is made of a claim for foreign	n priority under 35 U.S.C. § 119(a	n)-(d) or (f).			
	1. Certified copies of the priority document	ts have been received.	·			
	2. Certified copies of the priority document	ts have been received in Applicat	ion No			
	3. Copies of the certified copies of the prior	rity documents have been receiv	ed in this National Stage			
	application from the International Burea					
*;	See the attached detailed Office action for a list	of the certified copies not receive	ed.			
Attachme						
	ce of References Cited (PTO-892) ce of Draftsperson's Patent Drawing Review (PTO-948)	4) Interview Summary Paper No(s)/Mail D				
3) 🔲 Info	rmation Disclosure Statement(s) (PTO/SB/08)	5) 🔲 Notice of Informal I				
Pape	er No(s)/Mail Date	6)				

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DETAILED ACTION

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 4, 7 and 18 are rejected under 35 U.S.C. 102(b) as being anticipated by Shiota et al. (5,879,970).

Re claim 4, Shiota et al. discloses depositing an epitaxial layer based on Group IV elements a silicon substrate by Chemical Vapor Deposition using source gases (See abstract), and including employing nitrogen as a carrier gas, wherein the epitaxial layer comprises a SiGe epitaxial layer (Abstract and Col.6, lines 15-20).

Re claim 7, Shiota et al. disclose wherein the CVD process is carried out at a temperature that facilitates a CVD growth rate of an epitaxial layer that is substantially greater than a CVD growth rate of such an epitaxial layer using hydrogen as a carrier gas, since the same temperature is being used as the present invention (less than 600 °C).

Re claim 18, Shiota et al. discloses wherein the process is carried out at a temperature of less than about 600°C (see abstract, 350 °C to 450 °C).

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Allowable Subject Matter

Claims 5 and 19 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Michelle Estrada whose telephone number is 571-272-1858. The examiner can normally be reached on Monday through Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Matthew Smith can be reached on 571-272-1907. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 571-272-2800.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should Application/Control Number:

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you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Michelle Estrada Primary Examiner Art Unit 2823

ME December 5, 2007